TADsens: Transient Adjoint DAE Sensitivities

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Importance of Transient Sensitivities

- **Context**: transient circuit simulation
- Circuit parameters: MOSFET dimensions, resistors, capacitors, supply voltages, *etc.*
- Sensitivities = change in circuit output for a given change in parameter values



Circuit Representations

Device + network equations in terms of voltages, currents

$$\begin{array}{c} & & i(t) \\ & & & \\ & & \\ & & \\ i(t) = I_s(e^{-v(t)/V_T} - 1) \end{array}$$



DAE: system of differential and algebraic equations



algebraic

$$\begin{cases}
i(t) = I_S \left(\exp\left(\frac{u(t) - i(t)R - v(t)}{V_T}\right) - 1 \right) \\
\frac{dv}{dt} = \frac{i(t)}{C} \\
\text{differential}
\end{cases}$$

Direct Sensitivity Computation



- M(t) is a dense sensitivity matrix of size $nxn_{p, M}(t) = \frac{\partial \vec{x}}{\partial \vec{p}}$
- Solving the sensitivity DAE has complexity O(nn_nT)
- This is infeasible for circuits with large numbers of parameters



Adjoint Sensitivity Computation



- We typically care about only a few circuit outputs
- Complexity O((n+n_n)T): much more efficient than direct



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Sensitivity Computation – History

- Direct computation only:
 - D. Hocevar, P. Yang, T. Trick, and B. Epler, 1985
- Specialized techniques:

Only for a few circuit elements

- S. Director and R. Rohrer, 1969
- P. Feldmann, T. V. Nguyen, S. W. Director, and R. AmRiahrespiele 12
- A priori discretization:
 - F. Liu and P. Feldmann, 2014.
 - K.V. Aadithya, E. Keiter and T. Mei, 2017
 Onstraints on form of DAE
- ODEs or special DAE forms:
 ODE only
 - Y. Cao, S. Li, L. Petzold, and R. Serban, 2003.
 - A. Meir and J. Roychowdhury, 2012.

Adjoint Operators and Inner Products



Inner product relationship: $\langle \vec{x}(t), \vec{y}(t) \rangle = \langle \vec{u}(t), \vec{z}(t) \rangle$

Note: the inner product of two vector functions is defined as $\langle \vec{x}(t), \vec{y}(t) \rangle = \int \vec{y}^T(t) \vec{x}(t) dt$

Dirac δ Input into the Adjoint DAE



- This δ-function input allows us to isolates the sensitivities at time T via the adjoint inner product relationship.
- If we know the ASF, we can compute the sensitivities of o(T)



Consequences of δ -Function Input

- Problem: ∞-valued, cannot be accurately represented numerically
- Solution: assume the ASF is of the form

$$\vec{z}(t) = \vec{z}_1(t) + \vec{k}\delta(t-T)$$

- and analytically derive $ec{z_1(t)}$ and $ec{k}$



Deriving the ASF



Compute sensitivities using adjoint inner-product relationship

The Adjoint DAE



ASF for ODEs and Algebraic Equations



ASF for DAEs

 An impulsive input into the adjoint DAE results in an impulsive output superposed onto a finite waveform



Discontinuity in Computing the ASF



- Issues in numerically integrating z1(t) to get final sensitivities
- Solution: take a small first transient timestep and discard z1(T)

Results: Simple Size-2 DAE

- Goal: Illustrate using a hand-calculable example
- **System:** size-two DAE:
- RC ODE with separate algebraic equation added on



• Analytical sensitivities:

$$\frac{\partial \vec{x}}{\partial \vec{p}} = \begin{bmatrix} \frac{t}{R^2 C} (x_1(0) - V_{\rm in}) e^{-\frac{t}{RC}} & \frac{t}{C^2 R} (x_0 - V_{\rm in}) e^{-\frac{t}{RC}} \\ -\frac{t}{R^2 C} & -\frac{t}{RC^2} \end{bmatrix}$$

Results: Simple Size-2 DAE

- Setup: output = 2x1(t) + x2(t), R = 1 kΩ, C = 1 μF, T = 1 ms
- Plot: Analytical, direct, and adjoint sensitivities to R over time (change in output per percent change in R)



Results: Simple Size-2 DAE

ASF for T = 1 ms, o(t) = 2x1(t) + x2(t)



Sensitivities at T:

- To R: -1.3679e-03 V/Ohm
- To C: -1.3679e+06 V/F



Normalized by pNom value:

- To R: -1.3679e-02 V/%
- To C: -1.3679e-02 V/%

Results: 51-Stage MOS Ring Osc.

- Goal: Efficiency on a larger, more interesting circuit
- System: 51-stage MOS ring oscillator



155 unknowns, 664 parameters

Results: 51-Stage MOS Ring Osc.

Nominal Output Waveform



- Setup: 3000 timepoints over one oscillator period (T = 2.447 ms)
- Most important parameters: load capacitors at output of each inverter
- Runtime: direct = 7392 s, adjoint = 24.6 s

Results: 51-Stage MOS Ring Osc.

- Plot: sensitivities of output to load cap at output
- Normalized by nominal parameter value



Results: Sensitivity of Ring Oscillator Period



• **Result**: a 1% change in the output load capacitance will cause a 0.0209% change in the oscillator period

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Summary

Problem

 Devise an efficient and numerically well-defined method for computing sensitivities of circuit outputs via adjoints

